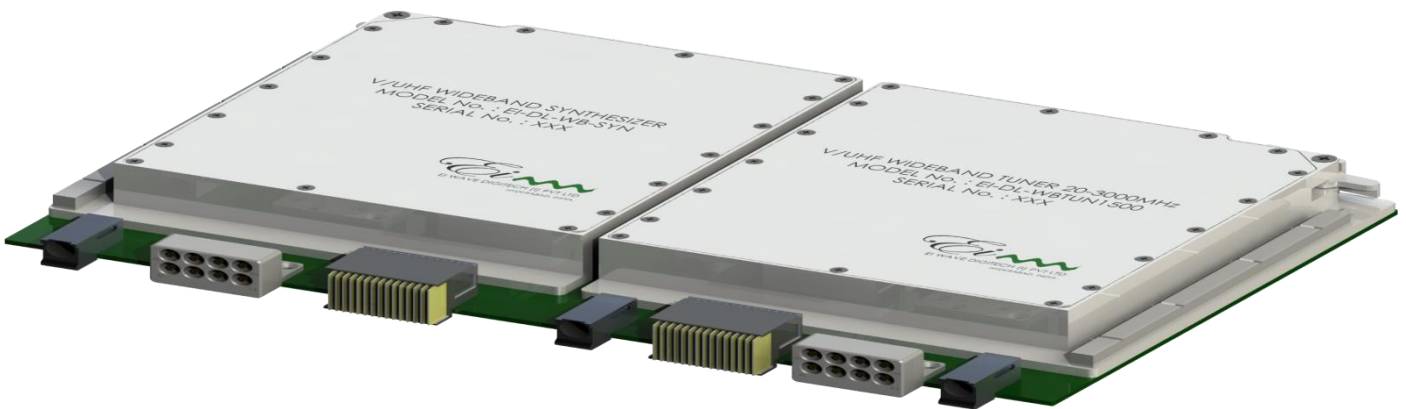


RF WIDEBAND TUNER (30-3000MHz)



The **EIWDTUN-20-3000**, is a single channel Wideband tuner with 40Mhz bandwidth and tuner is expandable to **100 kHz - 6 GHz**. RF Front end and synthesizer is integrated in a rugged, conduction-cooled 6U VPX module. Low Phase noise synthesizer and low noise figure front end makes this tuner suitable for communication intelligence (COMINT) and electronic intelligence (ELINT) application. For multi-channel additional RF tuners can be integrated to form a multi-channel radio solution These tuner can be user for DF application as Phase coherency is maintained. **EIWDTUN-20-3000** reduces manufacturing costs and improves production. It is designed for use in embedded applications where size, weight, and power are important factors.

Key features and benefits

- **Ultra low Phase noise** with fast tuning synthesizer.
- Single or multi-channel phase coherent operation
- High dynamic range is achieved with different mode of selection.
- Low Noise Mode, Normal Mode and Low distortion mode supported for high sensitivity and high dynamic range.
- A stable OCXO with very low ppm long term stability makes this tuner a perfect solution which can be used for years without any calibration.
- This Tuner is expandable to 100KHz - 6GHz.
- Sub-octave preselectors decrease inter-modulation products and increase dynamic range.
- Low spurs are achieved with variable reference technique.
- Inbuilt RF Byte source is provided for system failure testing.

EIWDTUN-20-3000 specifications

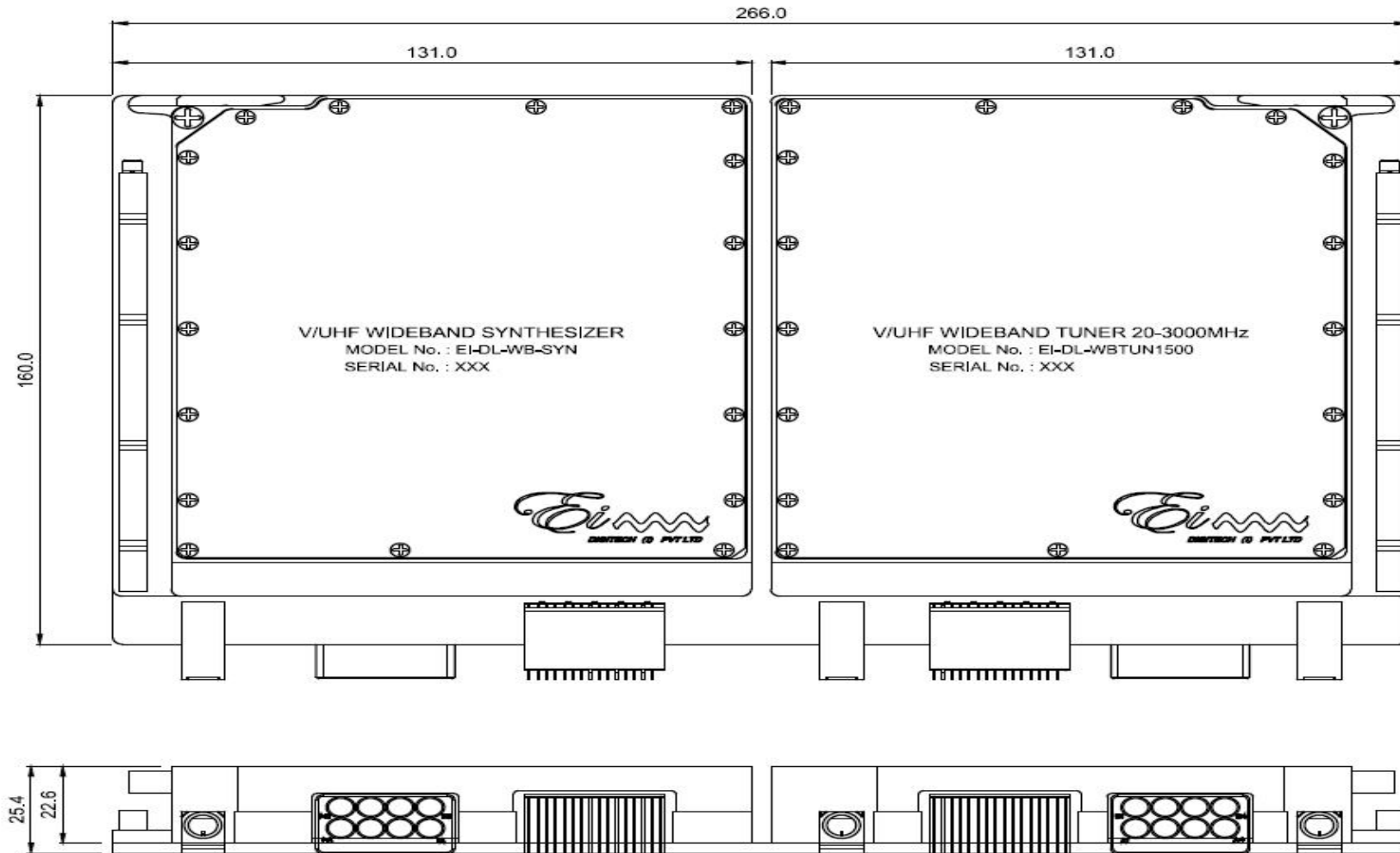
RF Front End specifications

Parameter	Specification
Tuning range	30 MHz to 3 GHz
Analog IF bandwidth	Selectable 40/0.3 MHz (Other options available)
Input impedance	50 ohms
VSWR	Less than 2.5:1
Preselection	Bypass, 20-90 MHz
90MHz to 3 GHz	Suboctave preselectors
Max input level	+ 30 dBm
Image rejection	> 90 dB
IF rejection	> 90 dB
LO re-radiation	< -90 dBm
Noise figure	14 dB typical (10 dB with pre-amp selected)
Third order intercept	+ 3 dBm (Low Noise Mode) +20 dBm typical (Normal Mode) +35dBm (Low Distortion Mode)
Single tone SFDR	> 80 dB
Internal spurious	< -110 dBm typical
Gain control	Attenuation range 60 dB with 1 dB steps 35dB Gain for Low Noise Mode 15dB Gain for Normal Mode 0dB Gain for Low Distortion Mode
AGC Output (70 MHz)	-10dBm \pm 2dBm

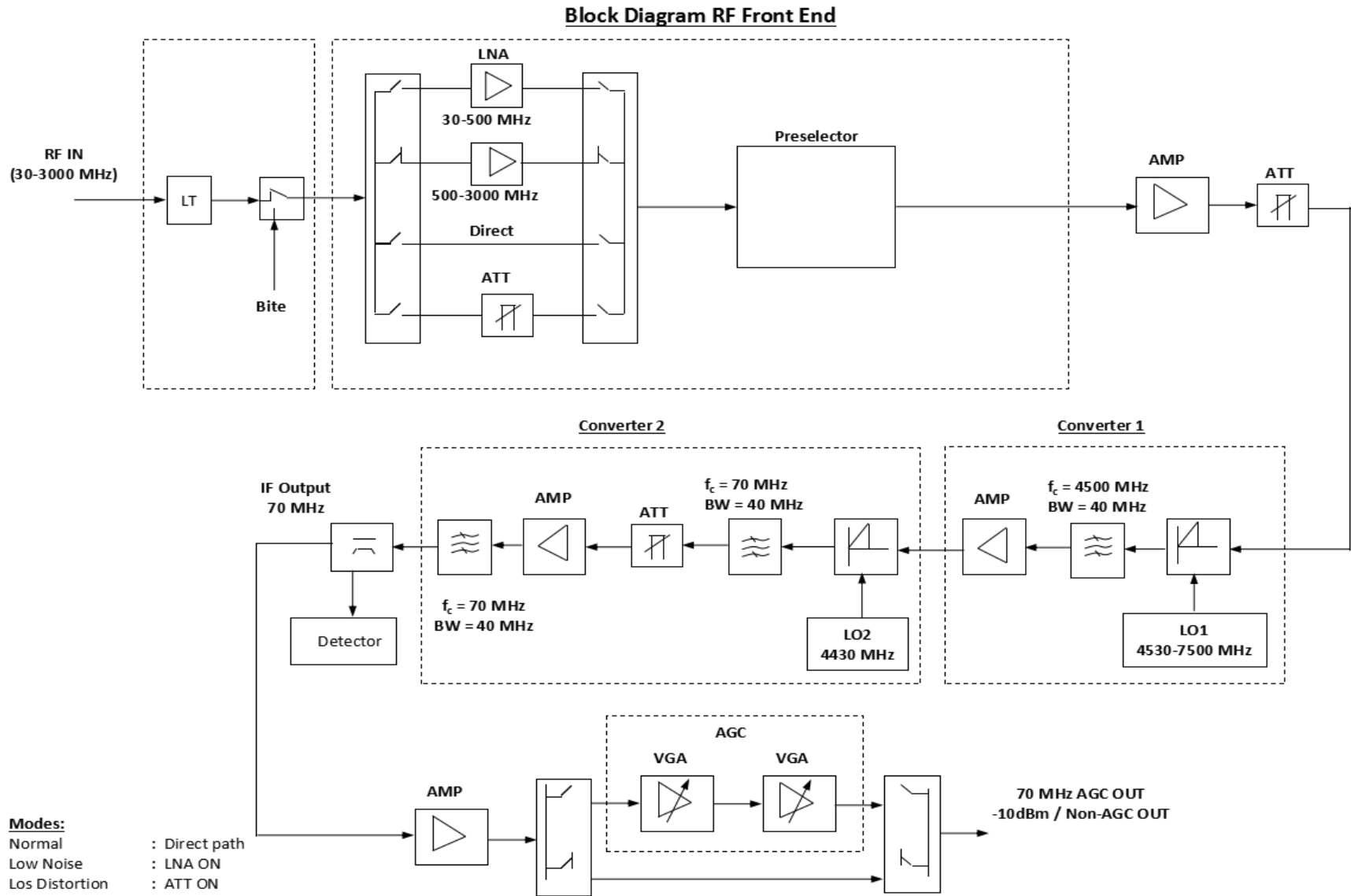
Synthesizer specifications

Parameter	Specification
RF tuning resolution	1 Hz via Second LO
RF tune speed	\leq 100 μ Sec
Phase Noise	90 dBc/Hz at 10KHz Offset (Typ.) LO1 95 dBc/Hz at 10KHz Offset (Typ.) LO2
Frequency Range	4530-7500MHz (LO1) 40MHz Step Size 4430 (LO2) 10Hz Step Size
Spurious	< 75dBc within 40MHz BW < 60dBc else-where
Output Power (LOs)	10dBm \pm 2dBm (LO1) 10dBm \pm 2dBm (LO2)
Reference	Internal Reference with 10ppb max External Reference 10MHz (0dBm) Option Reference Out for Frequency Coherency Option
RF Byte	30-3000MHz with 1KHz Step Size
Interface Specifications	
Digital Interface	Via backplane RS-232 SPI and other interfaces are optional
Power Supply Requirement	+12 (0.3A), +5.5V(3A), +3.63V(2A)
Mechanical/environmental specifications	
Size	6U-160 VPX 1 inch pitch
Weight	< 2Kg
Operating temperature	-40°C to 70°C
Storage temperature	-55°C to +85°C
EMI/EMC	MII-STD 461-E
Environmental	JS-S5555

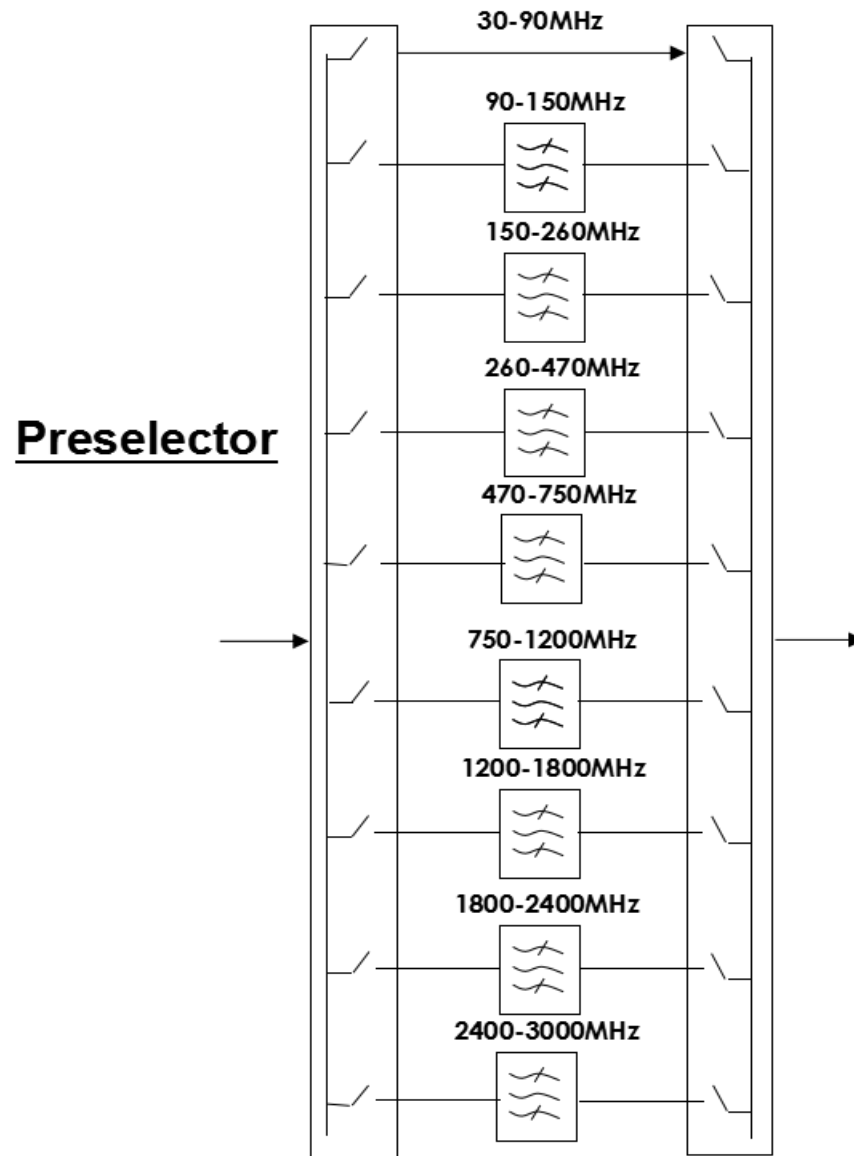
Mechanical



Block Diagram (RF Front End)



Block diagram of Preselector



Block diagram of synthesizer

BLOCK DIAGRAM OF SYNTHESIZER :

